506369487 11/24/2020

PATENT ASSIGNMENT COVER SHEET

Electronic Version v1.1 Stylesheet Version v1.2

EPAS ID: PAT6416243

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
Yu-Chieh Chou	11/16/2020
Tsung-Hsiang Lin	11/16/2020

RECEIVING PARTY DATA

Name:	Vanguard International Semiconductor Corporation	
Street Address:	123, Park Ave-3rd, Hsinchu Science Park	
City:	Hsinchu	
State/Country:	TAIWAN	

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	17102441

CORRESPONDENCE DATA

Fax Number:

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ATTORNEY DOCKET NUMBER:	VISP0056USA
NAME OF SUBMITTER:	SIBYL YU
SIGNATURE:	/SIBYL YU/
DATE SIGNED:	11/24/2020

Total Attachments: 4

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> **PATENT REEL: 054451 FRAME: 0718** 506369487

COMBINE DECLARATION (37 CFR 1.63) FOR UTILITY OR DESIGN APPLICATION USING AN APPLICATION DATA SHEET (37 CFR 1.76) AND ASSIGNMENT

Title of Invention: HIGH-VOLTAGE SEMICONDUCTOR STRUCTURE

As the below named inventor, I hereby declare that: This declaration is directed to:	
☑ The attached application, or	
☐ United States application number	, or
□ PCT international application number	filed on
The above-identified application was made or authorized t	to be made by me.
I believe that I am the original inventor or an original joint i application.	inventor of a claimed invention in the
l hereby acknowledge that any willful false statement mad under18 U.S.C. 1001 by fine or imprisonment of not more	le in this declaration is punishable than five (5) years, or both.
In consideration of the payment by Vanguard Internation Consideration of the payment by Semiconductor Constitution (Constitution of the payment by Semiconductor Constitution of the payment by Semiconductor Constitution (Constitution of the payment by Semiconductor Constitution of the payment by Semiconductor Constitution (Constitution of the payment by Semiconductor Constitution of the payment by Semiconductor Constitution (Constitution of the payment by Semiconductor (Con	having a postal address of Corporation
123, Park Ave-3rd, Hsinchu Science Park, Hsin	chu 30077, Taiwan, R.O.C.
(referred to as "ASSIGNEE"below) to I of the sum of One acknowledged, andfor other good and valuable considerate	Dollar (\$ 1.00), the receipt of which is hereby tion.
hereby sell, assign and transfer to ASSIGNEE and the state entire right, title and interest in and to any and all imprinvention as above-identified application and, in and to, all invention by the above application or any continuations, or substitutes, or extensions thereof, and as to Letters Paten	ovements which are disclosed in the I Letters Patent to be obtained for said ontinuation-in-part, divisions, renewals,
hereby covenant that no assignment, sale, agreement or entered into which would conflict with this assignment;	encumbrance has been or will be made or
further covenant that ASSIGNEE will, upon its request, be and documents relating to said invention and said Letters known and accessible to I and will testify as to the same in related thereto and will promptly execute and deliver to AS	Patent and legal equivalents as may be any interference, litigation proceeding
representatives any and all papers, instruments or affidavi maintain, issue and enforce said application, said inventio equivalents thereof which may be necessary or desirable to N WITNESS WHEREOF, I have hereunto set hand and s	n and said Letters Patent and said to carry out the proposes thereof,
Note: An application data sheet (PTO/SB/14 or equivalent inventive entity, must accompany this form. Use this form	

Page 1 of 4

NPO#VIS-P0056-USA:0 CUST#109020

F#NPO-P0002E-US1201 DSB0-109U042780 LEGAL NAME OF INVENTOR(ASSIGNOR)

Inventor:

Yu-Chieh Chou

Date

20 / 11 / 18 de

Signature:

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F#NPO-P0002E-US1201 DSB0-109U042780

NPO#VIS-P0056-USA:0 CUST#109020

> PATENT REEL: 054451 FRAME: 0720

COMBINE DECLARATION (37 CFR 1.63) FOR UTILITY OR DESIGN APPLICATION USING AN APPLICATION DATA SHEET (37 CFR 1.76) AND ASSIGNMENT

Title of Invention: HIGH-VOLTAGE SEMICONDUCTOR STRUCTURE

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☑ The attached application, or				
☐ United States application number		filed on, or		
□ PCT international application number		iled on		
The above-identified application was made or	authorized to be made by m	e.		
I believe that I am the original inventor or an or application.	riginal joint inventor of a clair	med invention in the		
I hereby acknowledge that any willful false statement made in this declaration is punishable under18 U.S.C. 1001 by fine or imprisonment of not more than five (5) years, or both.				
In consideration of the payment by Vangua Semico	ard International onductor Corporation	having a postal addi	ress of	
123, Park Ave-3rd, Hsinchu Science I	Park, Hsinchu 30077, Ta	iwan, R.O.C.		
(referred to as "ASSIGNEE"below) to I of the a acknowledged, andfor other good and valuable	sum of One Dollar (\$ 1.00), the consideration.	ne receipt of which is her	eby	
I hereby sell, assign and transfer to ASSIGNEE and the successors and assignees of the ASSIGNEE the entire right, title and interest in and to any and all improvements which are disclosed in the invention as above-identified application and, in and to, all Letters Patent to be obtained for said invention by the above application or any continuations, continuation-in-part, divisions, renewals, substitutes, or extensions thereof, and as to Letters Patent any reissue or re-examination thereof.				
I hereby covenant that no assignment, sale, agreement or encumbrance has been or will be made or entered into which would conflict with this assignment;				
I further covenant that ASSIGNEE will, upon its request, be provided promptly with all pertinent facts and documents relating to said invention and said Letters Patent and legal equivalents as may be known and accessible to I and will testify as to the same in any interference, litigation proceeding related thereto and will promptly execute and deliver to ASSIGNEE or its legal				
representatives any and all papers, instruments or affidavits required to apply for, obtain, maintain, issue and enforce said application, said invention and said Letters Patent and said equivalents thereof which may be necessary or desirable to carry out the proposes thereof. IN WITNESS WHEREOF, I have hereunto set hand and seal this on the date(s) indicated.				
Note: An application data sheet (PTO/SB/14 of inventive entity, must accompany this form. Use	or equivalent), including naming the this form for <u>each addition</u>	ng the entire al inventor.		

Page 3 of 4

NPO#VIS-P0056-USA:0 CUST#109020 F#NPO-P0002E-US1201 DSB0-109U042780

Docket No VISP0056USA

LEGAL NAME OF INVENTOR(ASSIGNOR)

Inventor: Tsung-Hsiang Lin Date: 2020, 11, 16

Signature: Tsung-Hsiang Lin

SA:0 Page 4 of 4

F#NPO-P0002E-US1201 DSB0-109U042780

PATENT REEL: 054451 FRAME: 0722

NPO#VIS-P0056-USA:0 CUST#109020

RECORDED: 11/24/2020